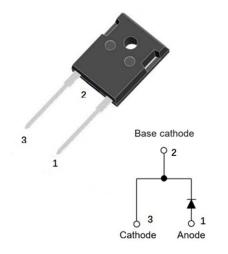
YJD112020NYG4

Silicon Carbide Schottky Diode

V _{RRM}	1200V
I _{F (135°C)}	27A
Q _c	118nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- Package: TO-247AC
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (Tc=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D112020NYG4
Reverse voltage (Repetitive peak) @ T _j =25°C	V _{RRM}	V	1200
Reverse voltage (Surge peak) @ T _j =25°C	V _{RSM}	V	1200
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	1200
Continuous forward current @ $T_c=25^{\circ}C$			59
Continuous forward current @ T _c =135°C	I _F	А	27
Continuous forward current @ T_c =151°C			20
Non-repetitive peak forward surge current @ T _c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	160
Power Dissipation@ T _c =25°C	Ρτοτ	W	230
Power Dissipation@ T _c =110°C	F TOT		100
i²t Value@ T _c =25°C ,tp=10ms	∫i²dt	A ² S	128
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175

1/5



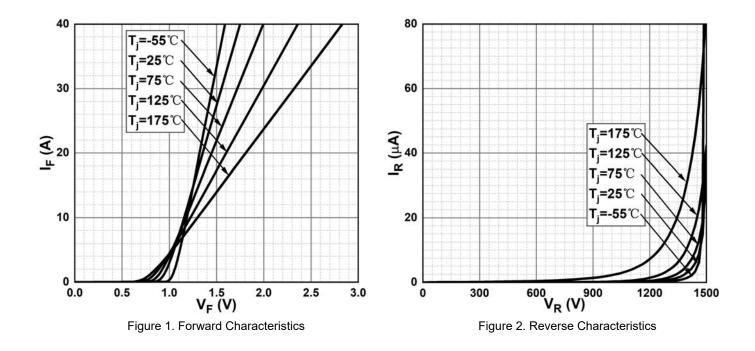
Electrical Characteristics

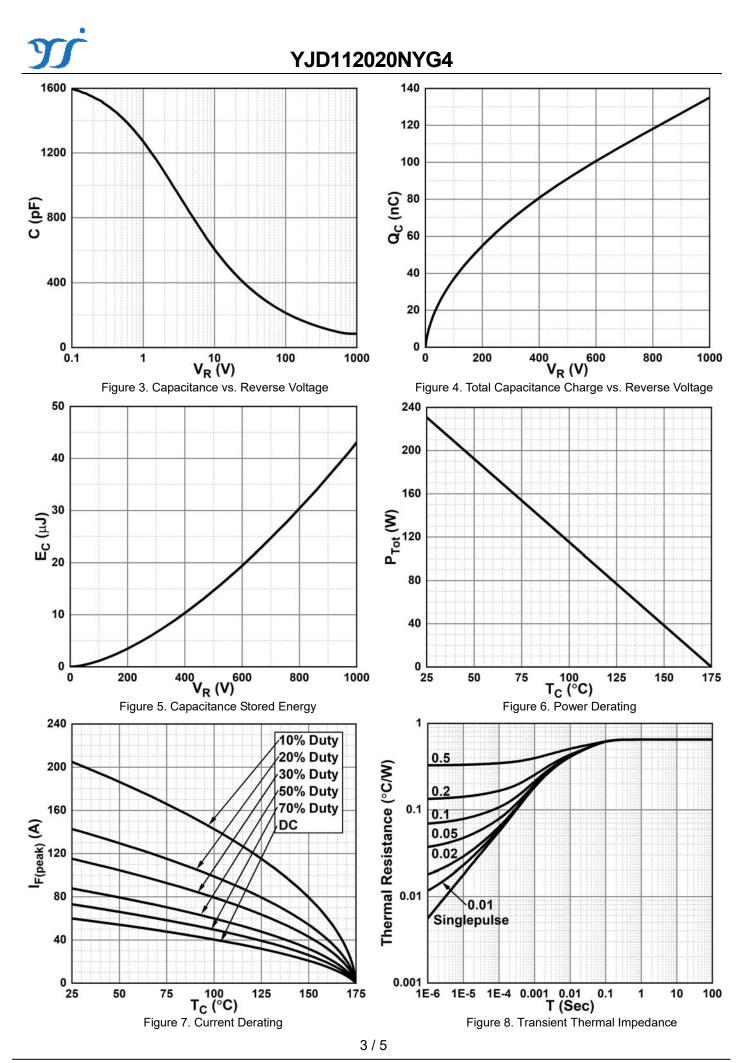
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drap		V	I _F =20A, T _j =25°C	1.36	1.60
Forward voltage drop	V _F		I _F =20A, T _j =175°C	1.85	-
Reverse current	1	l _R μA	V _R =1200V, T _j =25°C	0.5	25
Reverse current	I _R		V _R =1200V, T _j =175°C	10	-
Total capacitive charge	Qc	nC	V_R =800V, T _j =25°C , $Q_C = \int_0^{VR} C(V) dV$	118	-
		pF	V _R =0V, f=1MHZ	1626	-
Total capacitance	С		V _R =400V, f=1MHZ	110	-
			V _R =800V, f=1MHZ	85	-
Capacitance stored energy	Ec	μJ	V _R =800V	30	-

■Thermal Characteristics (Ta=25 °C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C /W	0.65

■Typical Characteristics





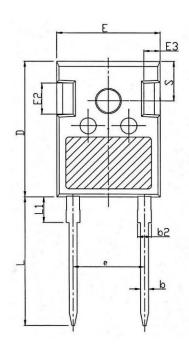
Yangzhou Yangjie Electronic Technology Co., Ltd.

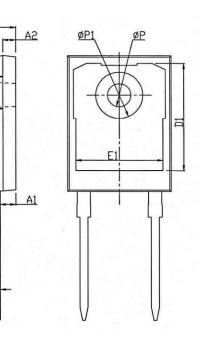


Outline Dimensions

TO-247AC

C





TO-247AC				
Dim	Min	Max		
А	4.80	5.20		
A1	2.21	2.61		
A2	1.85	2.15		
b	1.11	1.36		
b2	1.91	2.21		
С	0.51	0.75		
D	20.70	21.30		
D1	16.25	16.85		
Е	15.50	16.10		
E1	13.00	13.60		
E2	4.80	5.20		
E3	2.30	2.70		
е	10.88BSC			
L	19.62	20.22		
L1	-	4.30		
ΦP	3.40	3.80		
ΦP1	-	7.30		
S	6.15BSC			

4 / 5



YJD112020NYG4

Disclaimer

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